



QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS 10-BIT BUS SWITCH

IDTQS3384

FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- 5Ω bidirectional switches connect inputs to outputs
- Zero propagation delay, zero added ground bounce
- Undershoot clamp diodes on all switch and control inputs
- Two enables control five bits each
- Available in SOIC, QSOP, and TSSOP packages

APPLICATIONS:

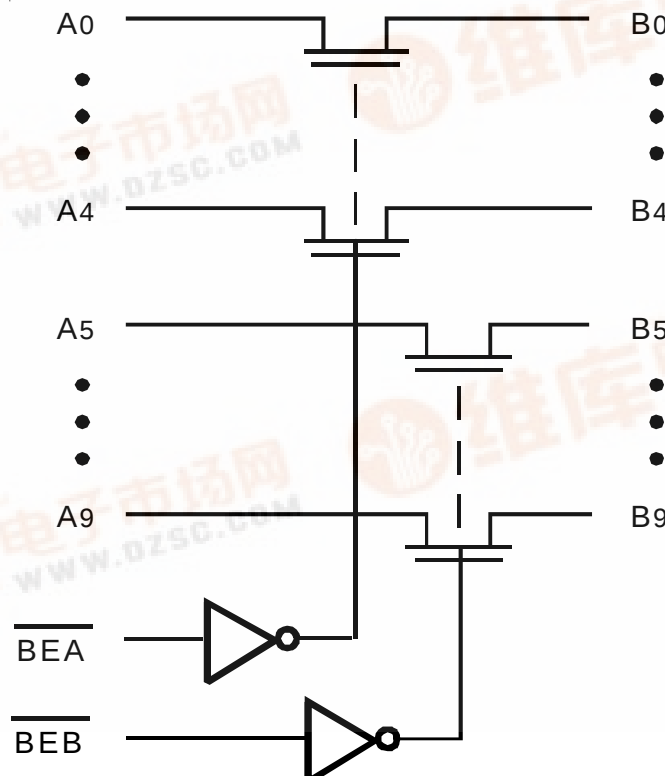
- Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Power Conservation
- Capacitance reduction and isolation
- Bus Isolation
- Clock Gating

DESCRIPTION:

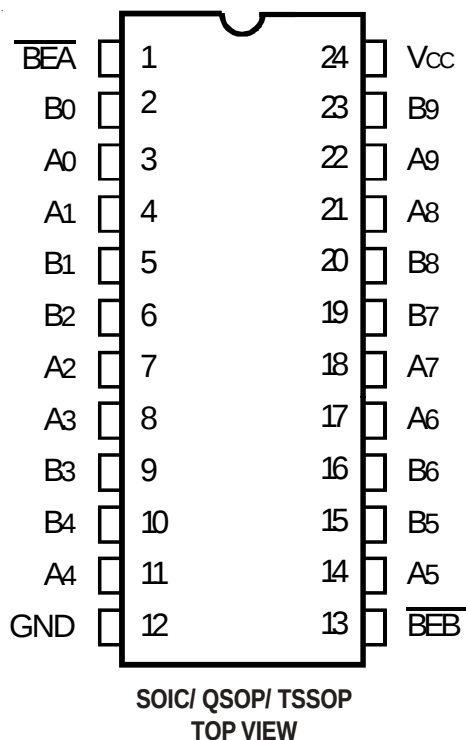
The QS3384 provides a set of ten high-speed CMOS, TTL-compatible bus switches. The low ON resistance of QS3384 allows inputs to be connected to outputs without adding propagation delay and without generating additional ground bounce. Two banks of 5 switches are controlled by independent Bus Enable ($\overline{BE}$) signals.

The QS3384 is characterized for operation at -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	-0.5 to +7	V
VTERM ⁽³⁾	DC Switch Voltage V _S	-0.5 to +7	V
VTERM ⁽³⁾	DC Input Voltage V _{IN}	-0.5 to +7	V
V _{AC}	AC Input Voltage (pulse width ≤20ns)	-3	V
I _{OUT}	DC Output Current	120	mA
P _{MAX}	Maximum Power Dissipation (T _A = 85°C)	0.5	W
T _{STG}	Storage Temperature	-65 to +150	°C

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{CC} terminals.
- All terminals except V_{CC}.

CAPACITANCE (T_A = +25°C, f = 1MHz, V_{IN} = 0V, V_{OUT} = 0V)

Pins	Typ.	Max. ⁽¹⁾	Unit
Control Inputs	3	5	pF
Quickswitch Channels (Switch OFF)	5	7	pF

NOTE:

- This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names	I/O	Description
A ₀ - A ₉	I/O	Bus A
B ₀ - B ₉	I/O	Bus B
$\overline{\text{BEA}}$, $\overline{\text{BEB}}$	I	Bus Switch Enable

FUNCTION TABLE⁽¹⁾

$\overline{\text{BEA}}$	$\overline{\text{BEB}}$	B ₀ - A ₄	B ₅ - B ₉	Function
H	H	Hi-Z	Hi-Z	Disconnect
L	H	A ₀ - A ₄	Hi-Z	Connect
H	L	Hi-Z	A ₅ - A ₉	Connect
L	L	A ₀ - A ₄	A ₅ - A ₉	Connect

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

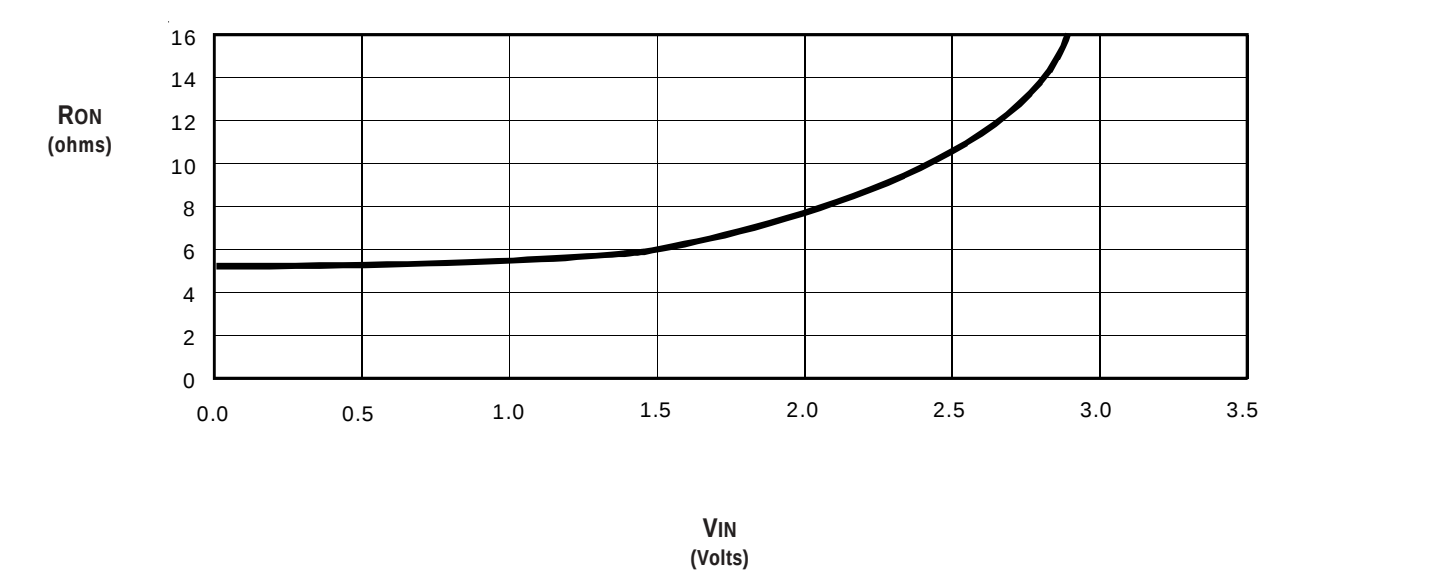
Industrial: TA = -40°C to +85°C, VCC = 5V ± 5%

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	—	—	V
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	—	—	0.8	V
IIN	Input Leakage Current (Control Inputs)	0V ≤ VIN ≤ VCC	—	±0.01	±1	μA
IOZ	Off-State Current (Hi-Z)	0V ≤ VOUT ≤ VCC, Switches OFF	—	±0.01	±1	μA
RON	Switch ON Resistance	VCC = Min., VIN = 0V, ION = 30mA	—	5	7	Ω
		VCC = Min., VIN = 2.4V, ION = 15mA	—	10	15	
VP	Pass Voltage ⁽²⁾	VIN = VCC = 5V, IOUT = -5μA	3.7	4	4.2	V

NOTES:

- 1. Typical values are at VCC = 5V and TA = 25°C.
- 2. Pass voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs VIN AT VCC = 5V



POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Max.	Unit
I _{CCQ}	Quiescent Power Supply Current	V _{CC} = Max., V _{IN} = GND or V _{CC} , f = 0	1.5	mA
ΔI _{CC}	Power Supply Current per Input HIGH ⁽²⁾	V _{CC} = Max., V _{IN} = 3.4V, f = 0	2.5	mA
I _{CCD}	Dynamic Power Supply Current per MHz ⁽³⁾	V _{CC} = Max., A and B Pins Open, Control Inputs Toggling @ 50% Duty Cycle	0.25	mA/MHz

NOTES:

- For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- Per TTL-driven input (V_{IN} = 3.4V, control inputs only). A and B pins do not contribute to ΔI_{CC}.
- This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T_A = -40°C to +85°C, V_{CC} = 5V ± 5%

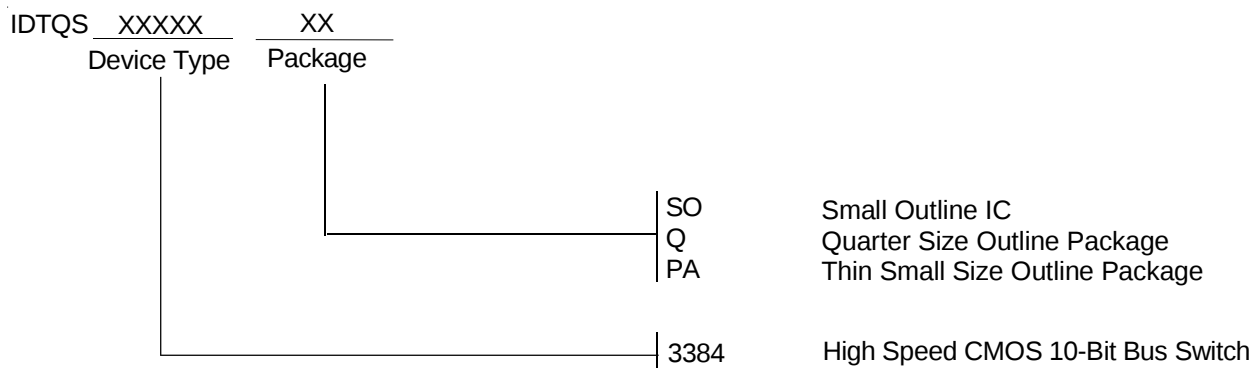
C_{LOAD} = 50pF, R_{LOAD} = 500Ω unless otherwise noted.

Symbol	Parameter	Min. ⁽¹⁾	Typ.	Max.	Unit
t _{PLH} t _{PHL}	Data Propagation Delay ⁽²⁾ A _x to B _x , B _x to A _x	—	—	0.25 ⁽³⁾	ns
t _{PZL} t _{PZH}	Switch Turn-On Delay $\overline{\text{BEA}}$, $\overline{\text{BEB}}$ to A _x , B _x	1.5	—	6.5	ns
t _{PLZ} t _{PHZ}	Switch Turn-Off Delay ⁽²⁾ $\overline{\text{BEA}}$, $\overline{\text{BEB}}$ to A _x , B _x	1.5	—	5.5	ns

NOTES:

- Minimums are guaranteed but not production tested.
- This parameter is guaranteed but not production tested.
- The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns at C_L = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION



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